

PJQ5466A1

60V N-Channel Enhancement Mode MOSFET

Voltage

60 V

Current

48 A

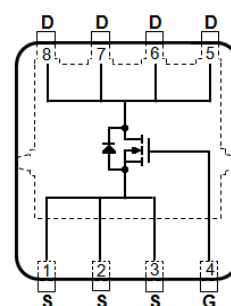
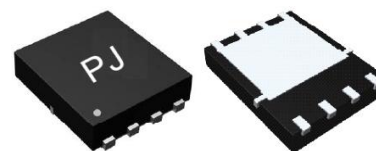
Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@20A < 17m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@10A < 20m\Omega$
- High switching speed
- Improved dv/dt capability
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: DFN5060-8L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0028 ounces, 0.08 grams

DFN5060-8L



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V_{DS}	60	V
Gate-Source Voltage		V_{GS}	+20	
Continuous Drain Current	$T_C=25^\circ\text{C}$	I_D	48	A
	$T_C=100^\circ\text{C}$		30	
Pulsed Drain Current (Note 1)	$T_C=25^\circ\text{C}$	I_{DM}	192	
Power Dissipation	$T_C=25^\circ\text{C}$	P_D	83	W
	$T_C=100^\circ\text{C}$		33	
Continuous Drain Current	$T_A=25^\circ\text{C}$	I_D	7.4	A
	$T_A=70^\circ\text{C}$		6.0	
Power Dissipation	$T_A=25^\circ\text{C}$	P_D	2.0	W
	$T_A=70^\circ\text{C}$		1.3	
Single Pulse Avalanche Energy (Note 6)		E_{AS}	45	mJ
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	$^\circ\text{C}$
Typical Thermal Resistance (Note 4,5)	Junction to Case	$R_{\theta JC}$	1.5	$^\circ\text{C/W}$
	Junction to Ambient	$R_{\theta JA}$	62.5	

- Limited only By Maximum Junction Temperature



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Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

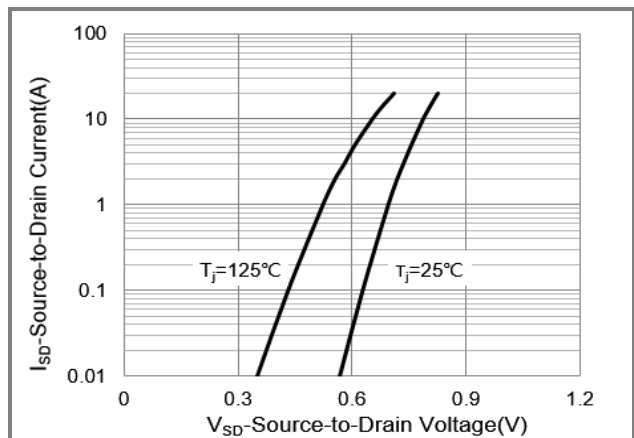
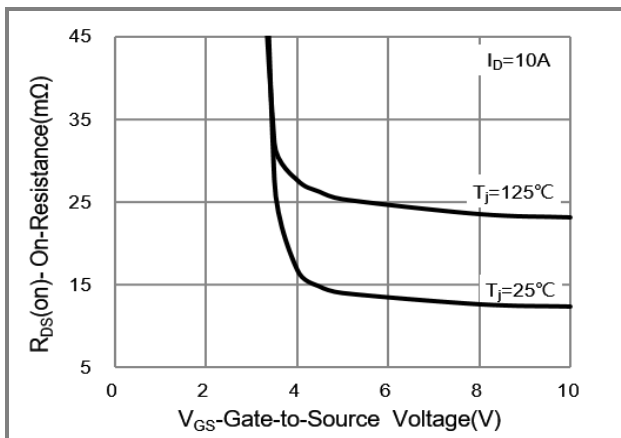
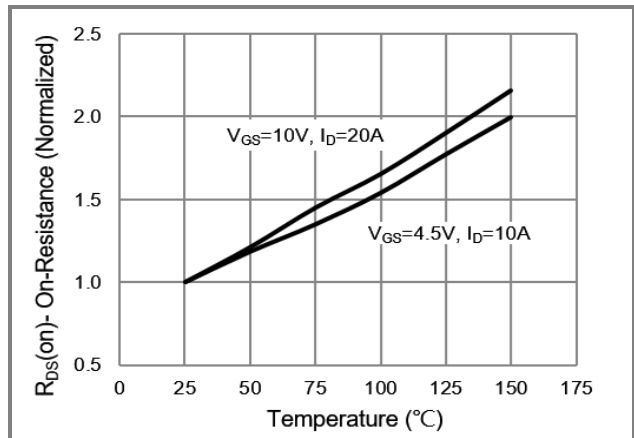
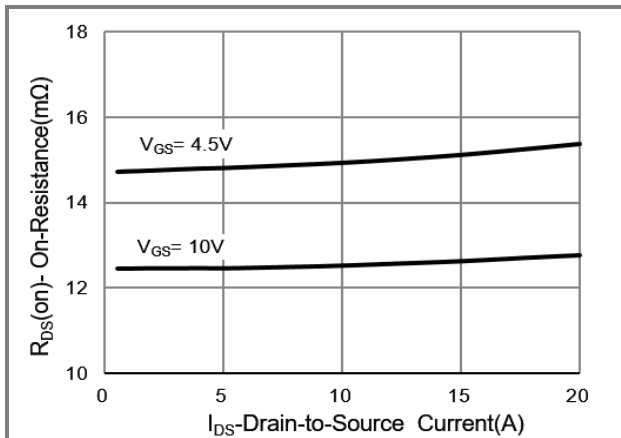
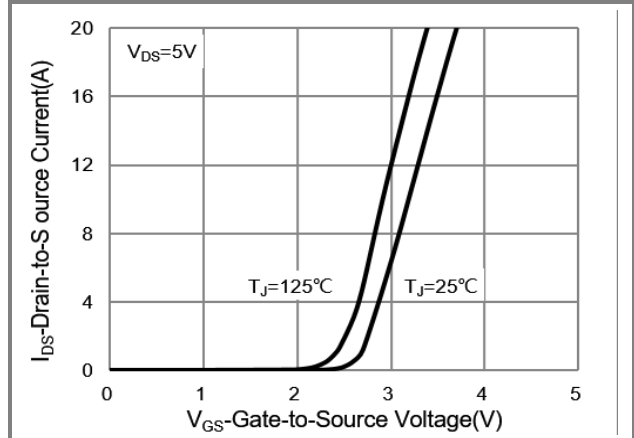
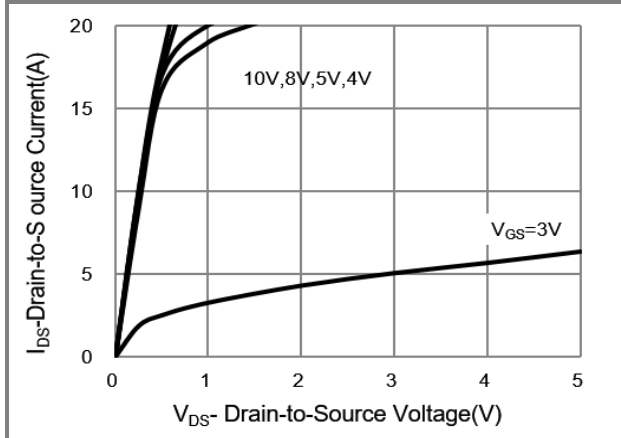
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	60	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250uA	1.0	1.7	2.5	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V, I _D =20A	-	13	17	mΩ
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =10A	-	15	20	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V, V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =+20V, V _{DS} =0V	-	-	+100	nA
Dynamic (Note 7)						
Total Gate Charge	Q _g	V _{DS} =30V, I _D =10A, V _{GS} =4.5V (Note 1,2)	-	13.5	-	nC
Gate-Source Charge	Q _{gs}		-	4.8	-	
Gate-Drain Charge	Q _{gd}		-	4.9	-	
Input Capacitance	C _{iss}	V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	1574	-	pF
Output Capacitance	C _{oss}		-	118	-	
Reverse Transfer Capacitance	C _{rss}		-	77	-	
Turn-On Delay Time	td(on)	V _{DD} =15V, I _D =1A, V _{GS} =10V, R _G =6Ω (Note 1,2)	-	11	-	ns
Turn-On Rise Time	t _r		-	11	-	
Turn-Off Delay Time	td(off)		-	35	-	
Turn-Off Fall Time	t _f		-	8.1	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S	---	-	-	48	A
Diode Forward Voltage	V _{SD}	I _S =1A, V _{GS} =0V	-	0.68	1	V

NOTES :

1. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150^{\circ}\text{C}$. Ratings are based on low frequency and duty cycles to keep initial $T_J=25^{\circ}\text{C}$.
4. The maximum current rating is package limited.
5. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
6. The test condition is $L=0.1\text{mH}$, $I_{AS}=30A$, $V_{DD}=25V$, $V_{GS}=10V$, Starting $T_J=25^{\circ}\text{C}$
7. Guaranteed by design, not subject to production testing.

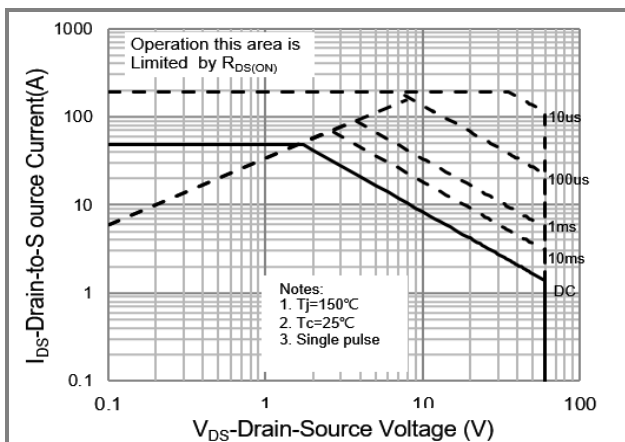
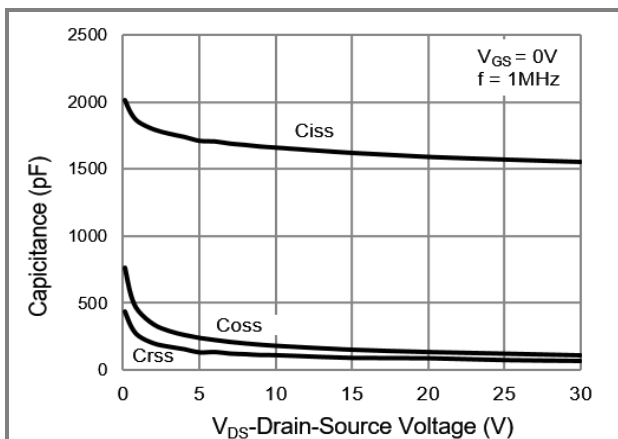
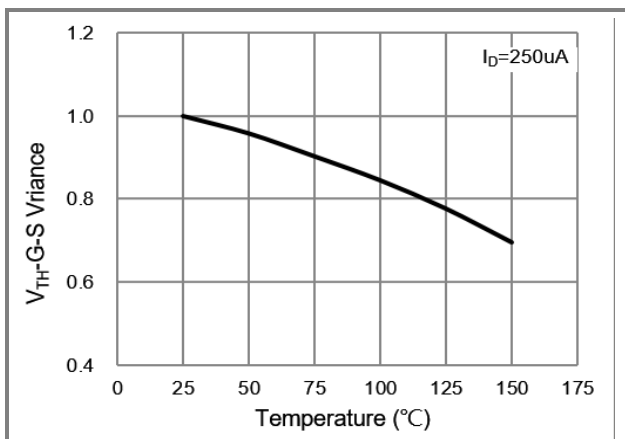
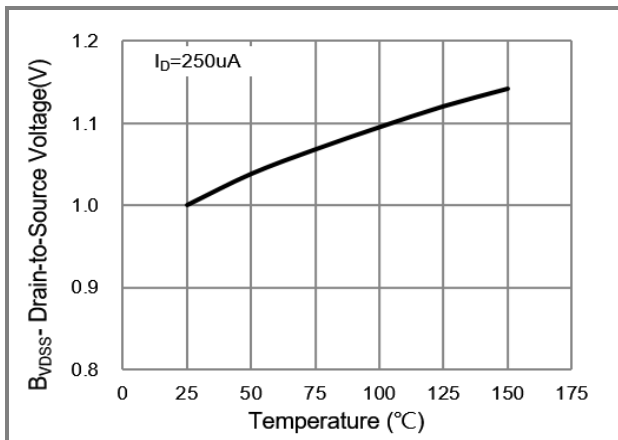
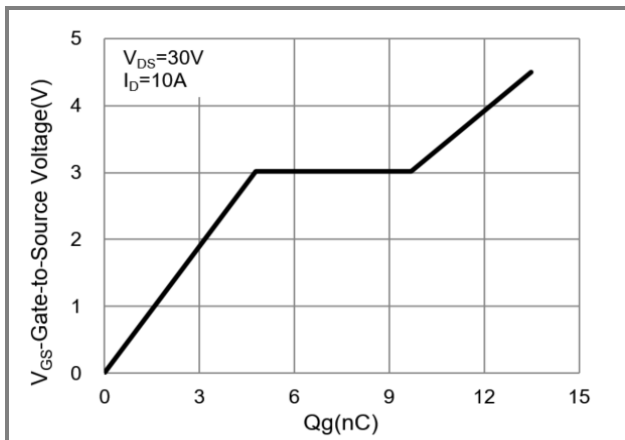
PJQ5466A1

TYPICAL CHARACTERISTIC CURVES



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TYPICAL CHARACTERISTIC CURVES

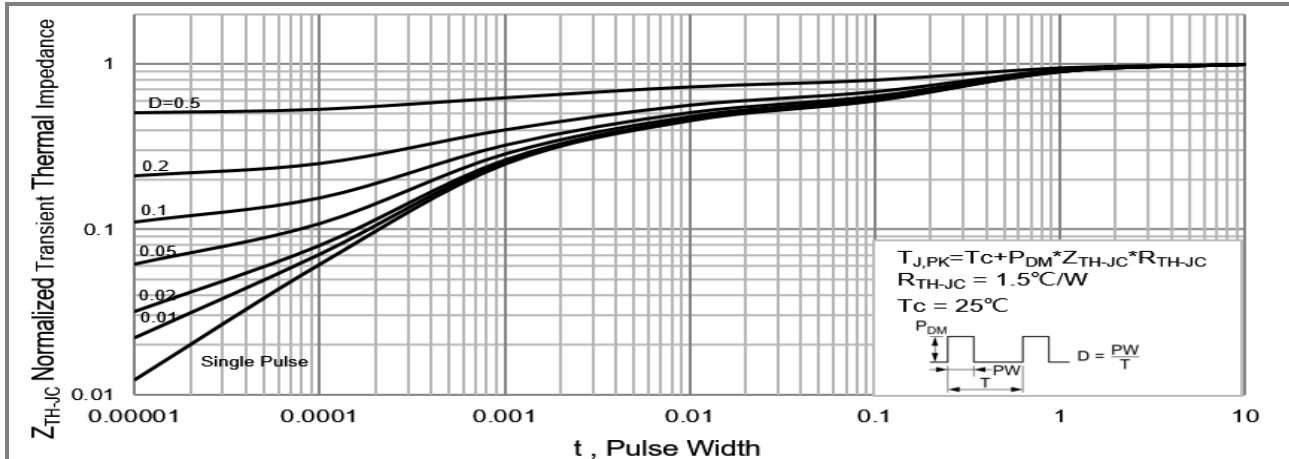


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

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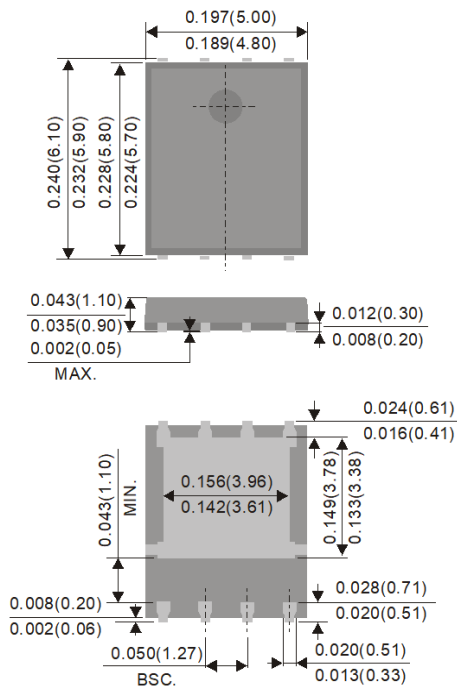
Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ5466A1_R2_00001	DFN5060-8L	3000pcs / 13" reel	Q5466A1	Halogen free

Packaging Information & Mounting Pad Layout

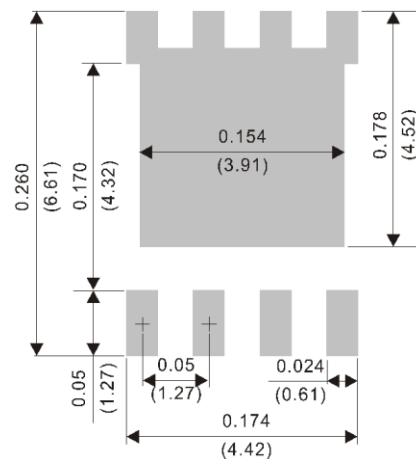
DFN5060-8L Dimension

Unit: inch(mm)



DFN5060-8L Pad Layout

Unit: inch(mm)





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